

## R-C Thermal Model Parameters

### DESCRIPTION

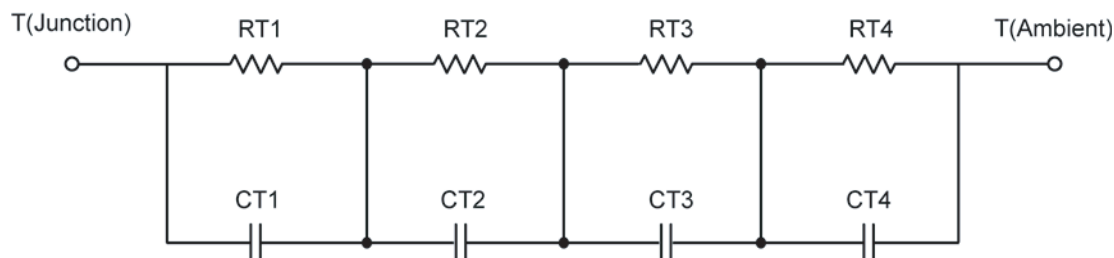
The parametric values in the R-C thermal model have been derived using curve-fitting techniques. These techniques are described in "[A Simple Method of Generating Thermal Models for a Power MOSFET](#)"[1]. When implemented in P-Spice, these values have matching characteristic curves to the Single Pulse Transient Thermal Impedance curves for the MOSFET.

R-C values for the electrical circuit in the Foster/Tank configuration are included. The corresponding values for the Cauer/Filter configuration are available upon request.

*Note:*

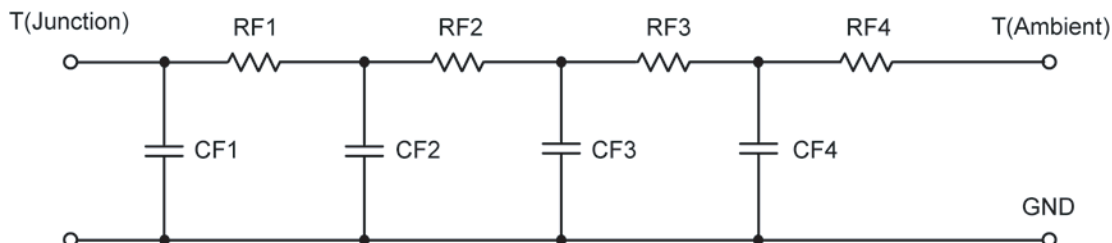
*For a detailed explanation of implementing these values in P-SPICE, refer to [Application Note AN609 Thermal Simulations Of Power MOSFETs on P-SPICE Platform](#).*

### R-C THERMAL MODEL FOR TANK CONFIGURATION



<b>R-C VALUES FOR TANK CONFIGURATION</b>			
Thermal Resistance (°C/W)			
Junction to	Ambient	Case	Foot
RT1	10.0692	N/A	8.6072
RT2	17.5132	N/A	1.1982
RT3	6.0839	N/A	3.2165
RT4	38.2266	N/A	6.9605
Thermal Capacitance (Joules/°C)			
Junction to	Ambient	Case	Foot
CT1	15.4756 m	N/A	2.9728 m
CT2	1.3203 m	N/A	736.7198 u
CT3	560.7579 m	N/A	13.6910 m
CT4	1.5684	N/A	3.4065 m

*This document is intended as a SPICE modeling guideline and does not constitute a commercial product data sheet. Designers should refer to the appropriate data sheet of the same number for guaranteed specification limits.*

**R-C THERMAL MODEL FOR FILTER CONFIGURATION**

<b>R-C VALUES FOR FILTER CONFIGURATION</b>			
<b>Thermal Resistance (<math>^{\circ}\text{C}/\text{W}</math>)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
RF1	15.7970	N/A	2.5867
RF2	12.3272	N/A	7.6648
RF3	10.4765	N/A	7.3328
RF4	33.3286	N/A	2.4236
<b>Thermal Capacitance (Joules/<math>^{\circ}\text{C}</math>)</b>			
<b>Junction to</b>	<b>Ambient</b>	<b>Case</b>	<b>Foot</b>
CF1	1.0253 m	N/A	482.4989 u
CF2	6.7963 m	N/A	958.4250 u
CF3	433.1103 m	N/A	222.3754 u
CF4	1.3016	N/A	2.0874 m

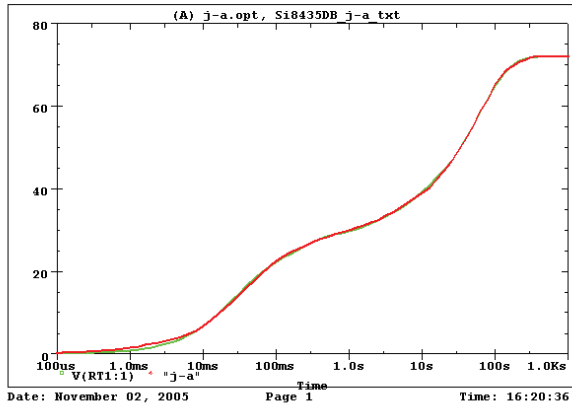
Note: NA indicates not applicable

Reference:

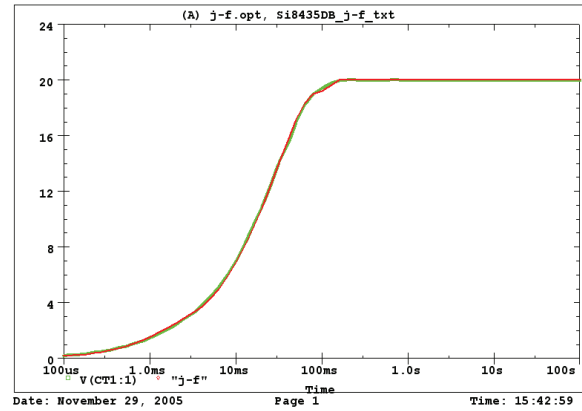
[1] "A Simple Method of Generating Thermal Models for a Power MOSFET" by Wharton McDaniel and Kandarp Pandya, IEEE / SEMITHERM 2002



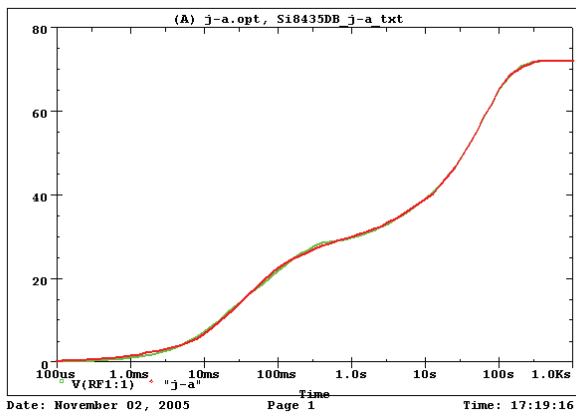
Si8435DB Tank j-a Temperature: 27.0



Si8435DB Tank j-f Temperature: 27.0



Si8435DB Filter j-a Temperature: 27.0



Si8435DB Filter j-f Temperature: 27.0

